Applications of Carbon Nanomaterials and Silicon-based Hybrid Composites in Lithium-ion Batteries

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By

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and Ruye Cong

Cambridge
Scholars
Publishing

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This book first published 2024

Cambridge Scholars Publishing

Lady Stephenson Library, Newcastle upon Tyne, NE6 2PA, UK

British Library Cataloguing in Publication Data
A catalogue record for this book is available from the British Library

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ISBN (10): 1-0364-0035-2
ISBN (13): 978-1-0364-0035-4

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